

35.C13630



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PATENT APPLICATION

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)
MASAAKI IWANE ET AL.) : Examiner: N/Y/A
Appln. No.: 09/346,678) : Group Art Unit: 2812
Filed: July 2, 1999) :
For: CRYSTAL GROWTH PROCESS,) :
SEMICONDUCTOR DEVICE, AND :
ITS PRODUCTION PROCESS) : March 8, 2000

Assistant Commissioner for Patents
Washington, D.C. 20231

REQUEST FOR CORRECTED FILING RECEIPT

Sir:

Applicants' attorneys have received an official Filing Receipt in the above-identified application in which the following inaccuracy is noted:

The name of the first inventor is incorrect and should read as follows: --MASAAKI IWANE--.

Issuance of a corrected Filing Receipt with the above noted corrections is respectfully requested.

Applicants' undersigned attorney may be reached in our New York office by telephone at (212) 218-2100. All correspondence should continue to be directed to our below listed address.

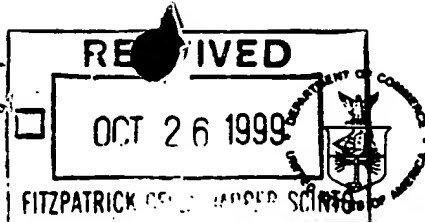
Respectfully submitted,


Attorney for Applicants

Registration No. 28 46

FITZPATRICK, CELLA, HARPER & SCINTO
30 Rockefeller Plaza
New York, New York 10112-3801
Facsimile: (212) 218-2200

FILING RECEIPT
CORRECTED

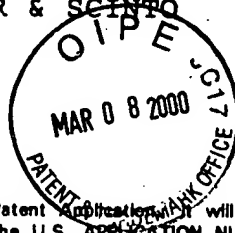


UNITED STATES DEPARTMENT OF COMMERCE
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APPLICATION NUMBER	FILING DATE	GRP ART UNIT	FIL FEE REC'D	ATTORNEY DOCKET NO.	DRWGS	TOT CL	IND CL
09/346,678	07/02/99	2812	\$890.00	35.C13630	9	9	3

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FITZPATRICK CELLA HARPER & SCINTO
30 ROCKEFELLER PLAZA
NEW YORK NY 10112



due by Ret.

Receipt is acknowledged of this nonprovisional Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Customer Service Center. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts of Application" ("Missing Parts Notice") in this application, please submit any corrections to this Filing Receipt with your reply to the "Missing Parts Notice." When the PTO processes the reply to the "Missing Parts Notice," the PTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s) NASAAKI IWANE, ATSUGI-SHI, JAPAN; KATSUMI NAKAGAWA,
ATSUGI-SHI, JAPAN; SHOJI NISHIDA, HIRATSUKA-SHI, JAPAN;
NORITAKA UKIYO, ATSUGI-SHI, JAPAN; YUKIKO IWASAKI,
ATSUGI-SHI, JAPAN; MASAKI MIZUTANI, ISEHARA-SHI, JAPAN.

FOREIGN APPLICATIONS-	JAPAN	10-202867	03/07/98
	JAPAN	11-188466	02/07/99

IF REQUIRED, FOREIGN FILING LICENSE GRANTED 08/03/99

TITLE

CRYSTAL GROWTH PROCESS, SEMICONDUCTOR DEVICE, AND ITS PRODUCTION
PROCESS

PRELIMINARY CLASS: 438

TC:
1001

DATA ENTRY BY: BATES, DIANE

TEAM: 03 DATE: 10/19/99

(See reverse for new important information)



Bib Data Sheet

**FILE COPY**UNITED STATES DEPARTMENT OF COMMERCE
Patent and Trademark OfficeAddress: COMMISSIONER OF PATENTS AND TRADEMARKS
Washington, D.C. 20231

SERIAL NUMBER 09/346,678	FILING DATE 07/02/1999 RULE -	CLASS 257	GROUP ART UNIT 2815	ATTORNEY DOCKET NO. 35.C13630
APPLICANTS MASA AKI IWANE, ATSUGI-SHI, JAPAN; KATSUMI NAKAGAWA, ATSUGI-SHI, JAPAN; SHOJI NISHIDA, HIRATSUKA-SHI, JAPAN; NORITAKA UKIYO, ATSUGI-SHI, JAPAN; YUKIKO IWASAKI, ATSUGI-SHI, JAPAN; MASAKI MIZUTANI, ISEHARA-SHI, JAPAN;				
** CONTINUING DATA ***** <i>[Signature]</i>				
** FOREIGN APPLICATIONS ***** JAPAN 10-202887 03/07/1998 JAPAN 11-188466 02/07/1999 <i>07/03/1998</i> <i>07/02/1999</i>				
IF REQUIRED, FOREIGN FILING LICENSE GRANTED ** 08/03/1999 -				
Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 (a-d) conditions <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after met Verified and Acknowledged <i>[Signature]</i> Examiner's Signature <i>[Initials]</i>		STATE OR COUNTRY JAPAN	SHEETS DRAWING 9	TOTAL CLAIMS 9
		INDEPENDENT CLAIMS 3		
ADDRESS FITZPATRICK CELLA HARPER & SCINTO 30 ROCKEFELLER PLAZA NEW YORK, NY 10112				
TITLE CRYSTAL GROWTH PROCESS, SEMICONDUCTOR DEVICE, AND ITS PRODUCTION PROCESS				
FILING FEE RECEIVED 890	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:		<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit	